

UNIVERSITY OF CALIFORNIA, SANTA BARBARA
Department of Electrical and Computer Engineering

Homework 2 – due November 2, 2017 by 5:00pm

1. A student goes into lab to make a Hall measurement. She applies an x directed electric field and a z directed magnetic field to her sample, and then measures the y directed Hall voltage between points A and B . However, points A and B are misaligned on the x axis, with a separation Δx . This separation causes an additional voltage between the contacts; therefore, the voltage that she measures is not the Hall voltage.

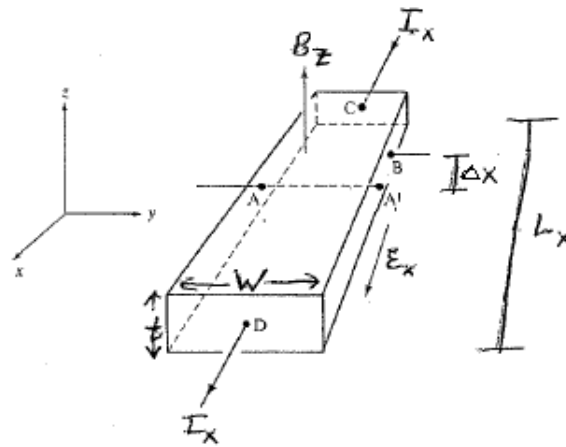


FIG. 1: Hall measurement setup

- (a) Suggest a simple procedure to get the correct Hall voltage from this setup, if the sample is n -type. Aligning the contacts is not an option.
- (b) Repeat part (a) for p -type.
2. An n -type silicon sample with $n_0 = 4 \times 10^{16} \text{ cm}^{-3}$ is excited with a pulse of light at $t = 0$ which results in an excess carrier concentration of $1 \times 10^{14} \text{ EHP/cm}^3$.
- (a) If the hole lifetime $\tau_p = 1 \mu\text{s}$, find an expression for the hole concentration as a function of time $p(t)$.
- (b) What is the hole concentration after one hole lifetime (τ_p) has elapsed?

3. A silicon sample with 10^{16} cm^{-3} donors is optically excited by a laser such that 10^{19} cm^{-3} electron-hole pairs (EHPs) are generated per second uniformly in the sample. The laser causes the sample to heat up to 450 K. Find the quasi-Fermi levels and the change in conductivity of the sample upon shining the light. Assume the electron and hole lifetimes are both $10 \mu\text{s}$, $D_p = 12 \text{ cm}^2/\text{s}$, $D_n = 36 \text{ cm}^2/\text{s}$, and $n_i = 10^{14} \text{ cm}^{-3}$ at 450 K.
4. The current required to feed the hole injection at $x = 0$ in Streetman Fig. 4-17 is obtained by evaluating the following equation at $x = 0$:

$$J_p(x) = -qD_p \frac{dp}{dx} = -qD_p \frac{d\delta p}{dx} = q \frac{D_p}{L_p} \Delta p e^{-x/L_p} = q \frac{D_p}{L_p} \delta p(x)$$

The result is $I_p(x = 0) = qAD_p\Delta p/L_p$. Show that this current can be calculated by integrating the charge stored in the steady state hole distribution $\delta p(x)$ and then dividing by the average hole lifetime τ_p . Explain why this approach gives us the correct expression for $I_p(x = 0)$.

5. Reading Assignment: *Streetman*: Ch. 3 and 4 (all)